



Attorney Docket No. 51876.P451

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Patent Application of:

Sang-Tae Ahn

Serial No. 10/741,791

Filed: December 19, 2003

**METHOD FOR FORMING FLOWABLE
DIELECTRIC LAYER IN SEMICONDUCTOR
DEVICE**

Examiner: Evan T. Pert

Art Unit: 2826

Mail Stop Issue Fee
Commissioner for Patents
PO Box 1450
Alexandria, Virginia 22313-1450

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EP 6/17/06*

AMENDMENT UNDER 37 C.F.R. § 1.312

Dear Commissioner:

After having received a Notice of Allowance dated January 30, 2006 in connection with the above-identified patent application, Applicant respectfully requests entry of the following amendments.



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